

IGBT (NPT) Module

$$V_{CES} = 1200V$$

$$I_{C25} = 90A$$

$$V_{CE(sat)} = 2.2V$$


Buck Chopper + free wheeling Diode

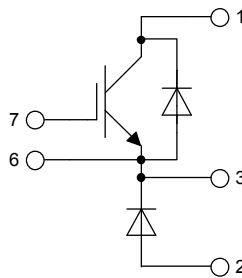
Part number

MDI75-12A3



Backside: isolated

 E72873



Features / Advantages:

- NPT IGBT technology
- low saturation voltage
- low switching losses
- switching frequency up to 30 kHz
- square RBSOA, no latch up
- high short circuit capability
- positive temperature coefficient for easy parallelling
- MOS input, voltage controlled
- ultra fast free wheeling diodes

Applications:

- AC motor drives
- Solar inverter
- Medical equipment
- Uninterruptible power supply
- Air-conditioning systems
- Welding equipment
- Switched-mode and resonant-mode power supplies
- Inductive heating, cookers
- Pumps, Fans

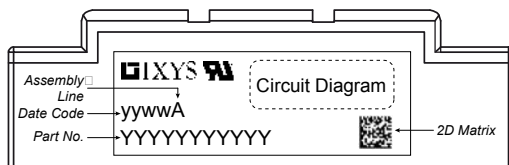
Package: Y4

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Free Wheeling Diode FWD				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
V_{RSM}	max. non-repetitive reverse blocking voltage				1200	V	
V_{RRM}	max. repetitive reverse blocking voltage				1200	V	
I_R	reverse current, drain current	$V_R = 1200\text{ V}$			650	μA	
		$V_R = 1200\text{ V}$			2	mA	
V_F	forward voltage drop	$I_F = 50\text{ A}$			2.50	V	
		$I_F = 100\text{ A}$			3.00	V	
		$I_F = 50\text{ A}$	$T_{VJ} = 125^\circ\text{C}$			1.90	V
		$I_F = 100\text{ A}$	$T_{VJ} = 125^\circ\text{C}$			2.30	V
I_{FAV}	average forward current	$T_C = 80^\circ\text{C}$			60	A	
		DC current	$d = 1$	$T_{VJ} = 150^\circ\text{C}$			
V_{FO}	threshold voltage	} for power loss calculation only			1.30	V	
r_F	slope resistance				12	m Ω	
R_{thJC}	thermal resistance junction to case				0.66	K/W	
R_{thCH}	thermal resistance case to heatsink			0.66		K/W	
P_{tot}	total power dissipation		$T_C = 25^\circ\text{C}$		190	W	
I_{FSM}	max. forward surge current	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}; V_R = 0\text{ V}$		$T_{VJ} = 45^\circ\text{C}$	400	A	
C_J	junction capacitance	$V_R = 600\text{ V}$ $f = 1\text{ MHz}$		$T_{VJ} = 25^\circ\text{C}$	30	pF	

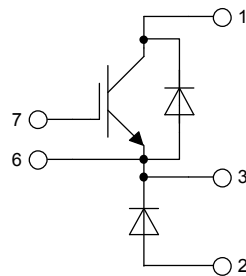
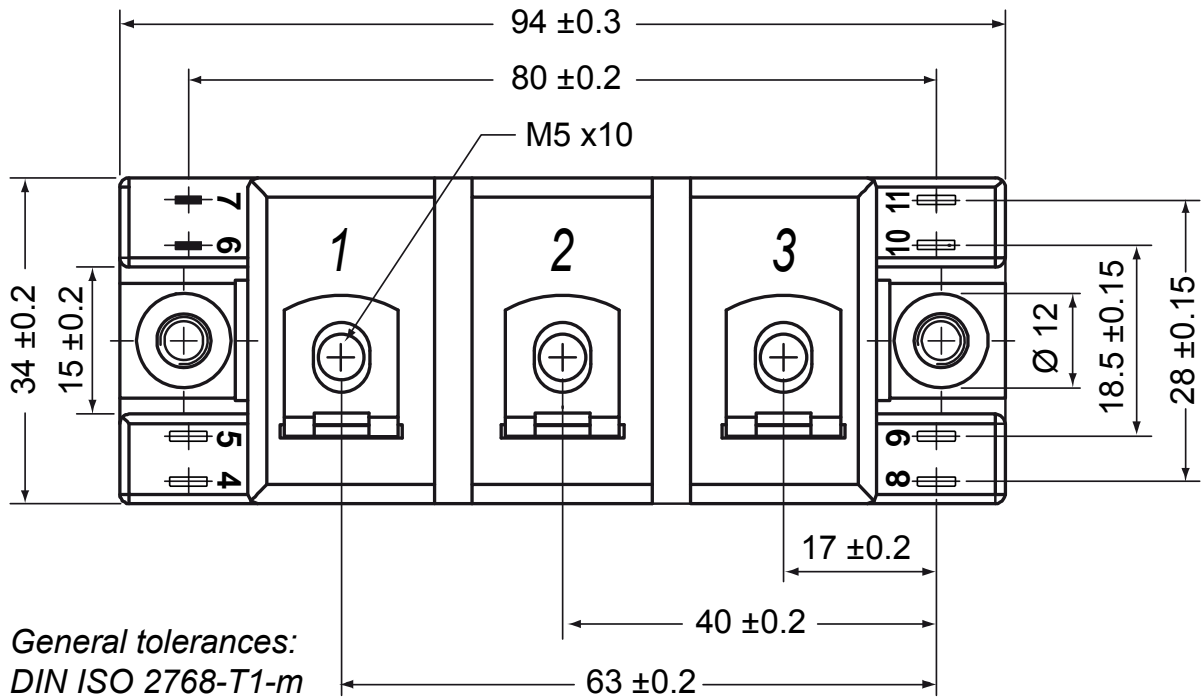
Buck IGBT				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
V_{CES}	collector emitter voltage	$T_{VJ} = 25^{\circ}\text{C}$			1200	V	
V_{GES}	max. DC gate voltage				± 20	V	
V_{GEM}	max. transient gate emitter voltage				± 30	V	
I_{C25}	collector current	$T_C = 25^{\circ}\text{C}$			90	A	
I_{C80}		$T_C = 80^{\circ}\text{C}$			60	A	
P_{tot}	total power dissipation	$T_C = 25^{\circ}\text{C}$			370	W	
$V_{CE(sat)}$	collector emitter saturation voltage	$I_C = 50\text{A}; V_{GE} = 15\text{V}$			2.2	V	
					2.7	V	
$V_{GE(th)}$	gate emitter threshold voltage	$I_C = 2\text{mA}; V_{GE} = V_{CE}$	4.5	5.5	6.5	V	
I_{CES}	collector emitter leakage current	$V_{CE} = V_{CES}; V_{GE} = 0\text{V}$			4	mA	
					6	mA	
I_{GES}	gate emitter leakage current	$V_{GE} = \pm 20\text{V}$			200	nA	
$Q_{G(on)}$	total gate charge	$V_{CE} = 600\text{V}; V_{GE} = 15\text{V}; I_C = 50\text{A}$		240		nC	
$t_{d(on)}$	turn-on delay time	inductive load $V_{CE} = 600\text{V}; I_C = 50\text{A}$ $V_{GE} = \pm 15\text{V}; R_G = 22\ \Omega$		100		ns	
t_r	current rise time			70		ns	
$t_{d(off)}$	turn-off delay time			500		ns	
t_f	current fall time			70		ns	
E_{on}	turn-on energy per pulse			7.6		mJ	
E_{off}	turn-off energy per pulse			5.6		mJ	
RBSOA	reverse bias safe operating area	$V_{GE} = \pm 15\text{V}; R_G = 22\ \Omega$					
I_{CM}		$V_{CEmax} = 1200\text{V}$			100	A	
SCSOA	short circuit safe operating area	$V_{CEmax} = 1200\text{V}$					
t_{sc}	short circuit duration	$V_{CE} = 1200\text{V}; V_{GE} = \pm 15\text{V}$			10	μs	
I_{sc}	short circuit current	$R_G = 22\ \Omega; \text{non-repetitive}$		180		A	
R_{thJC}	thermal resistance junction to case				0.33	K/W	
R_{thCH}	thermal resistance case to heatsink				0.33	K/W	
Buck Diode BD							
V_{RRM}	max. repetitive reverse voltage	$T_{VJ} = 25^{\circ}\text{C}$			1200	V	
I_{F25}	forward current	$T_C = 25^{\circ}\text{C}$			100	A	
I_{F80}		$T_C = 80^{\circ}\text{C}$			60	A	
V_F	forward voltage	$I_F = 50\text{A}$			2.50	V	
				1.80		V	
I_R	reverse current	$V_R = V_{RRM}$			0.65	mA	
				1		mA	
Q_{rr}	reverse recovery charge	$V_R = 600\text{V}$ $-di_F/dt = 400\text{A}/\mu\text{s}$ $I_F = 50\text{A}; V_{GE} = 0\text{V}$		3.5		μC	
I_{RM}	max. reverse recovery current			40		A	
t_{rr}	reverse recovery time			200		ns	
E_{rec}	reverse recovery energy			1		mJ	
R_{thJC}	thermal resistance junction to case				0.66	K/W	
R_{thCH}	thermal resistance case to heatsink				0.66	K/W	

Package Y4				Ratings		
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			300	A
T_{VJ}	virtual junction temperature		-40		150	°C
T_{op}	operation temperature		-40		125	°C
T_{stg}	storage temperature		-40		125	°C
Weight					108	g
M_D	mounting torque		2.25		2.75	Nm
M_T	terminal torque		4.5		5.5	Nm
$d_{Sppl/App}$	creepage distance on surface striking distance through air	terminal to terminal	14.0	10.0		mm
$d_{Spb/Apb}$		terminal to backside	16.0	16.0		mm
V_{ISOL}	isolation voltage	t = 1 second			3600	V
		t = 1 minute	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA		3000	V

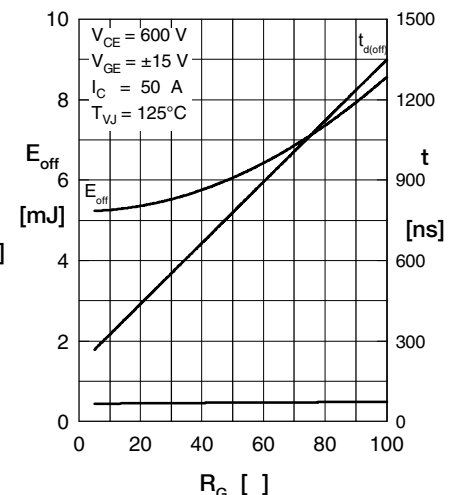
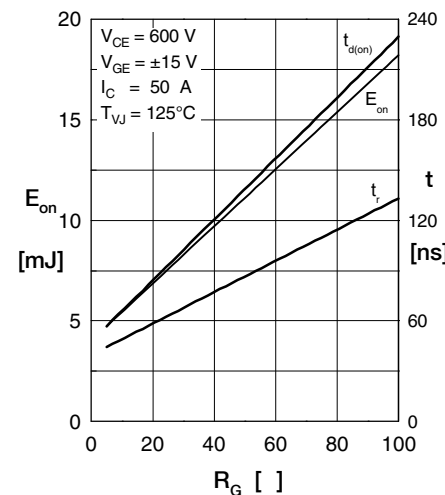
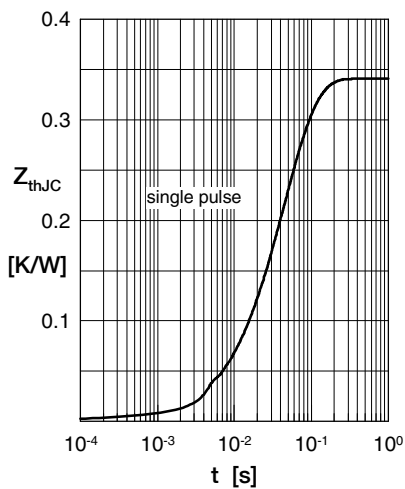
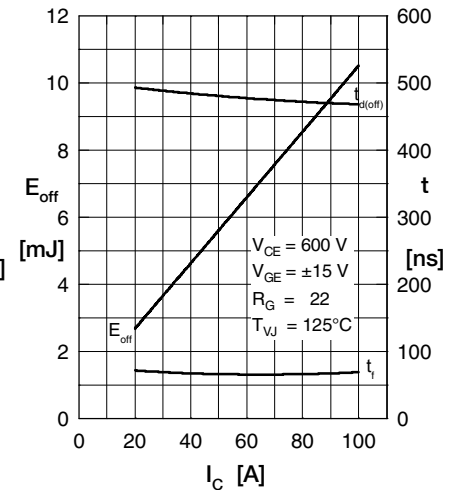
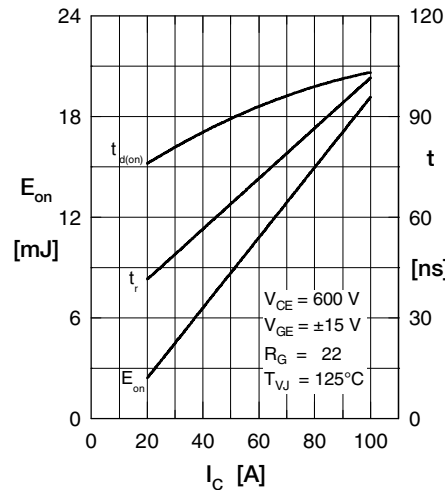
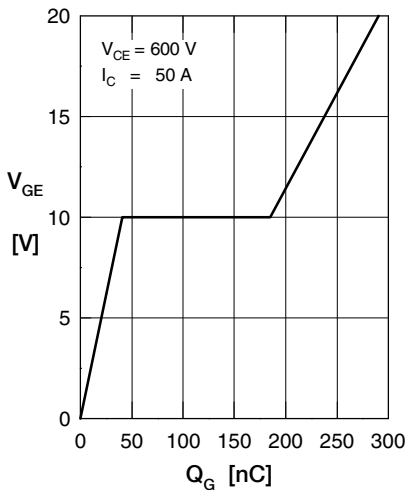
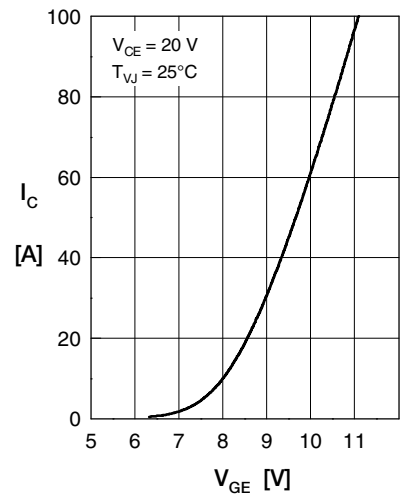
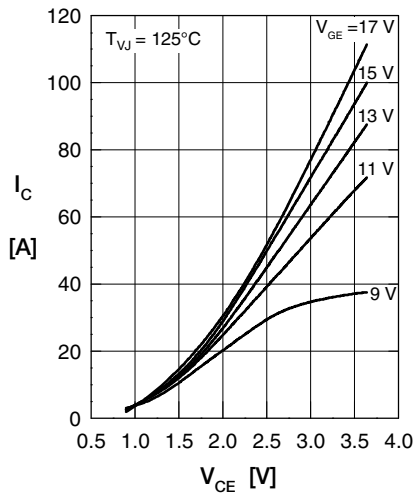
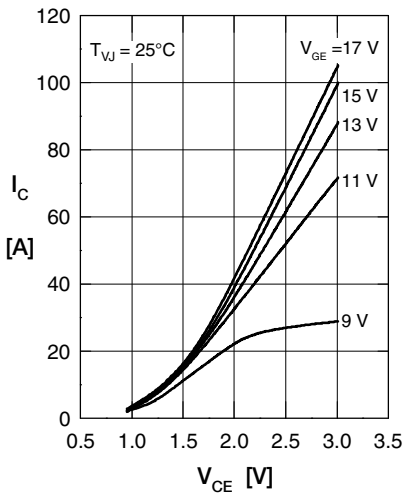


Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MDI75-12A3	MDI75-12A3	Box	6	474207

Outlines Y4



Buck IGBT



Buck Diode BD

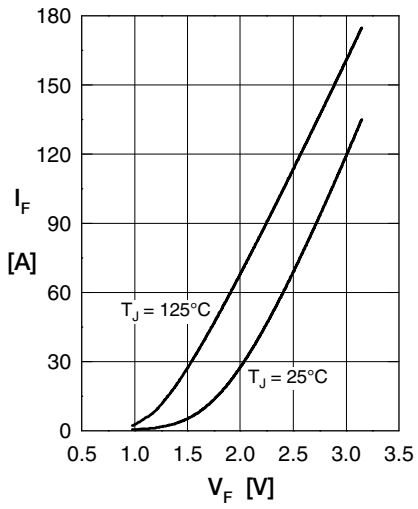


Fig. 1 Typ. Forward current vs. V_F

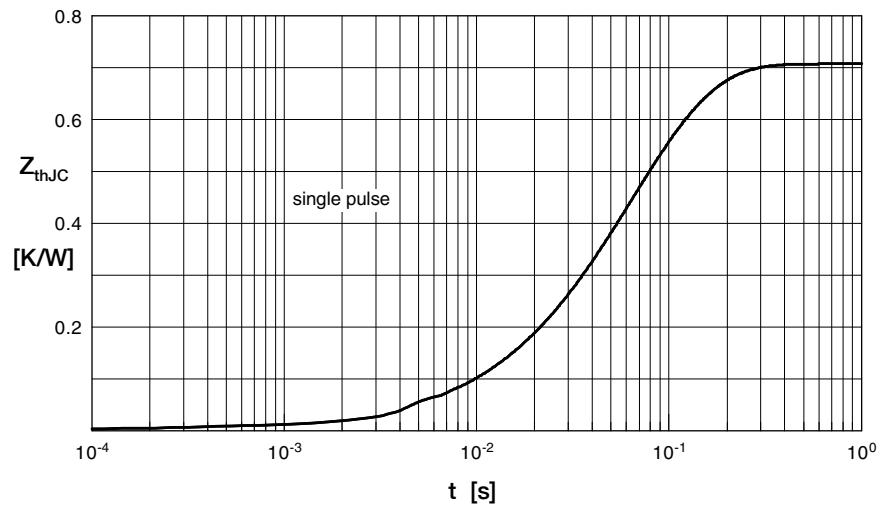


Fig. 2 Typ. transient thermal impedance junction to case

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